

|                     |                                                                                                                                               | acteristic<br>Typ. | Values<br>Max. |           |
|---------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|--------------------|----------------|-----------|
| g <sub>fs</sub>     | V <sub>DS</sub> = 20V, I <sub>D</sub> = 0.5 • I <sub>D25</sub> , Note 1                                                                       | 30                 | 48             | S         |
| C <sub>iss</sub>    |                                                                                                                                               |                    | 6800           | pF        |
| C <sub>oss</sub>    | $V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$                                                                                                         |                    | 680            | pF        |
| C <sub>rss</sub>    |                                                                                                                                               |                    | 44             | pF        |
| t <sub>d(on)</sub>  | Resistive Switching Times $V_{GS} = 10V, \ V_{DS} = 0.5 \bullet V_{DSS}, \ I_{D} = 0.5 \bullet I_{D25}$ $R_{G} = 1\Omega \ (\text{External})$ |                    | 22             | ns        |
| t,                  |                                                                                                                                               |                    | 11             | ns        |
| t <sub>d(off)</sub> |                                                                                                                                               |                    | 40             | ns        |
| t,                  |                                                                                                                                               |                    | 8              | ns        |
| Q <sub>g(on)</sub>  |                                                                                                                                               |                    | 108            | nC        |
| Q <sub>gs</sub>     | $V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_{D} = 0.5 \cdot I_{D2S}$                                                                   |                    | 37             | nC        |
| $\mathbf{Q}_{gd}$   |                                                                                                                                               |                    | 38             | nC        |
| R <sub>thJC</sub>   |                                                                                                                                               |                    |                | 0.13 °C/W |
| R <sub>thCS</sub>   |                                                                                                                                               |                    | 0.25           | °C/W      |

## 

## Source-Drain Diode

| Symbol                                             | Test Conditions                                        | Characteristic Values |      |      |    |
|----------------------------------------------------|--------------------------------------------------------|-----------------------|------|------|----|
| (T <sub>J</sub> = 25°C Unless Otherwise Specified) |                                                        | Min.                  | Тур. | Max. |    |
| I <sub>s</sub>                                     | $V_{GS} = 0V$                                          |                       |      | 52   | Α  |
| I <sub>SM</sub>                                    | Repetitive, Pulse Width Limited by $\rm T_{_{\rm JM}}$ |                       |      | 204  | Α  |
| V <sub>SD</sub>                                    | $I_F = I_S$ , $V_{GS} = 0V$ , Note 1                   |                       |      | 1.5  | V  |
| t <sub>rr</sub>                                    | $I_{F} = 26A, -di/dt = 100A/\mu s$                     |                       | 400  |      | ns |
|                                                    | $V_{R} = 100V, V_{GS} = 0V$                            |                       |      |      |    |

Note 1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .

## PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.